

Supporting information

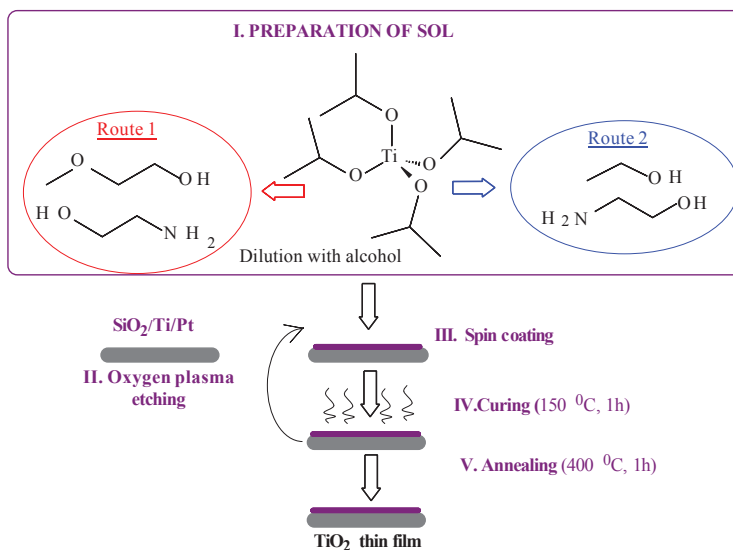


Fig. S1. Key steps of TiO₂ thin films preparation.

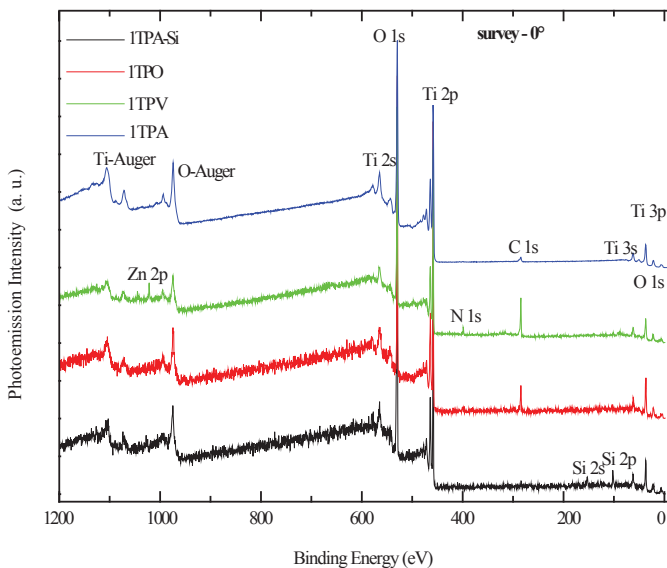


Fig. S2. Surveys of TiO₂ samples annealed in air (ITPA), oxygen (ITPO), vacuum (ITPV), and Si-contaminated oven (ITPA-Si).

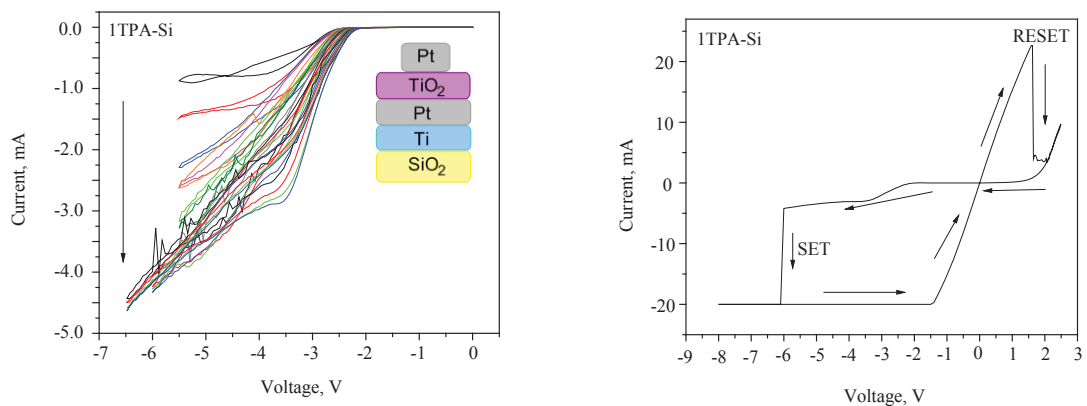


Fig. S3. Gradual electroforming of ITPA-Si with a compliance current of 20 mA and 60 s sweeps (left). First SET (20 mA compliance current, 60 s) and RESET (30 mA compliance current, 60 s) of ITPA-Si (right).

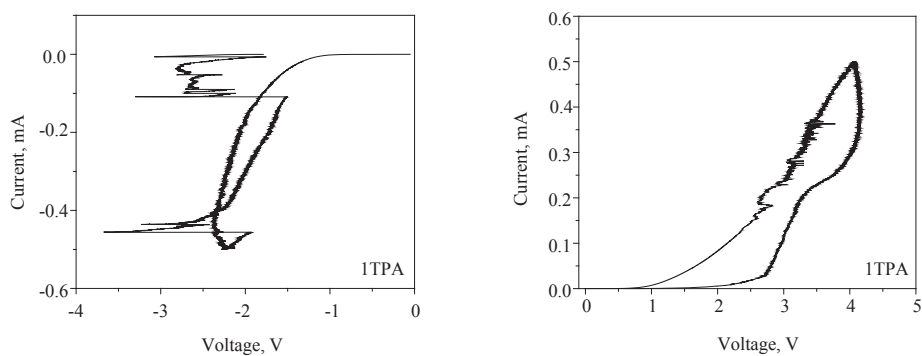


Fig. S4. Current-controlled electroforming of ITPA with Pt top dish electrode, $\pm 500 \mu\text{A}$ sweep with 100 nA step and a compliance current of 15 V.

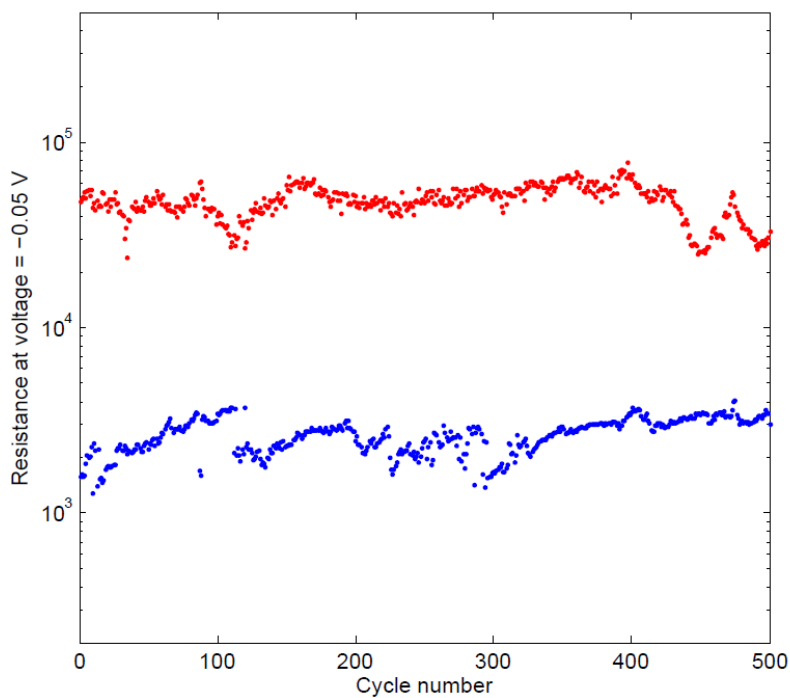


Fig. S5. Endurance of ITPA with Pt top dish electrode.